

Journal Name

ARTICLE

Electronic Supplementary Information

Non-equilibrium synthesis and characterization of n-type $\text{Bi}_2\text{Te}_{2.7}\text{Se}_{0.3}$ thermoelectric material prepared by rapid laser melting and solidification

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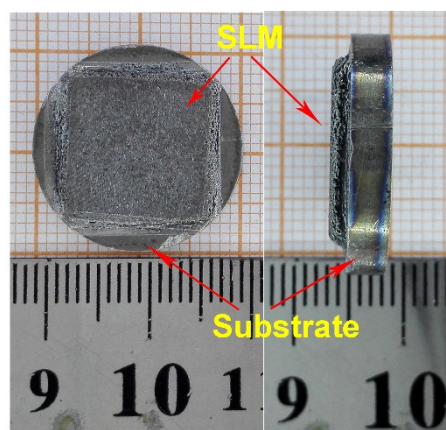


Figure S1 Photos of the SLM-prepared bulk sample

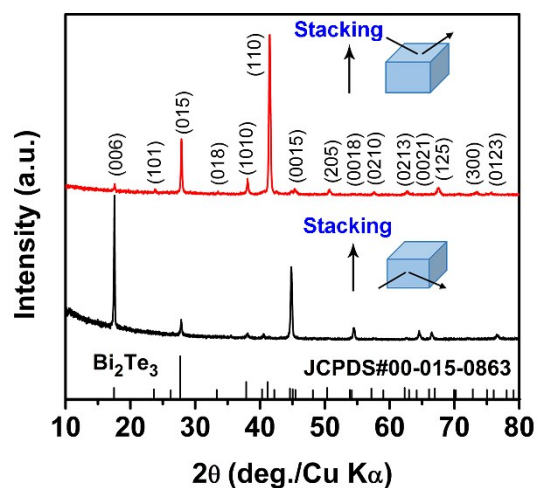


Figure S2 XRD patterns of the SLM-prepared bulk sample collected on planes perpendicular and parallel to the stacking direction

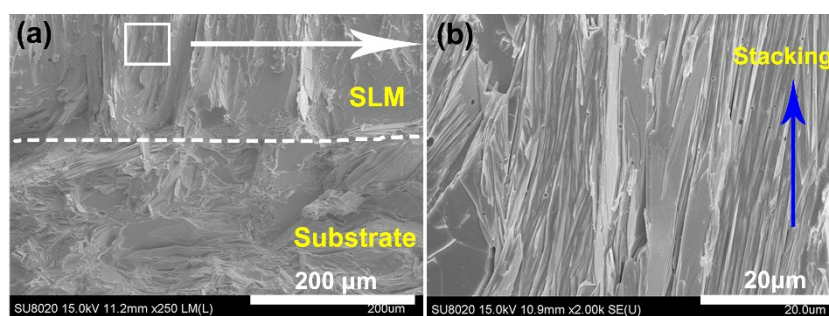


Figure S3 SEM images showing the microstructure of the cross section of the SLM-prepared bulk sample: (a) SLM fabricated layers attached to an n-type $\text{Bi}_2\text{Te}_{2.7}\text{Se}_{0.3}$ substrate; (b) enlarged area of (a) delineated by a white square showing aligned grains along the stacking direction